



PSMN1R1-25YLC

N-channel 25 V 1.15 mΩ logic level MOSFET in LPAK using NextPower technology

Rev. 1 — 2 May 2011

Product data sheet

1. Product profile

1.1 General description

Logic level enhancement mode N-channel MOSFET in LPAK package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High reliability Power SO8 package, qualified to 175°C
- Optimised for 4.5V Gate drive utilising NextPower Superjunction technology
- Ultra low QG, QGD and QOSS for high system efficiencies at low and high loads
- Ultra low R_{ds(on)} and low parasitic inductance

1.3 Applications

- DC-to-DC converters
- Lithium-ion battery protection
- Load switching
- Power OR-ing
- Server power supplies
- Sync rectifier

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------|----------------------------------|---|----------------------|------|------|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | - | - | 25 | V |
| I _D | drain current | T _{mb} = 25 °C; V _{GS} = 10 V; see Figure 1 | 11 - | - | 100 | A |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see Figure 2 | - | - | 215 | W |
| T _j | junction temperature | | -55 | - | 175 | °C |
| Static characteristics | | | | | | |
| R _{DS(on)} | drain-source on-state resistance | V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; see Figure 12 | - | 1.2 | 1.5 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; see Figure 12 | - | 0.95 | 1.15 | mΩ |

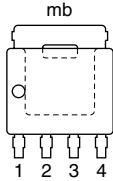
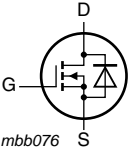
Table 1. Quick reference data ...continued

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-------------------|--|-----|-----|-----|------|
| Dynamic characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $V_{GS} = 4.5\text{ V}$; $I_D = 25\text{ A}$; $V_{DS} = 12\text{ V}$; see Figure 14 ; see Figure 15 | - | 11 | - | nC |
| $Q_{G(tot)}$ | total gate charge | $V_{GS} = 4.5\text{ V}$; $I_D = 25\text{ A}$; $V_{DS} = 12\text{ V}$; see Figure 15 ; see Figure 14 | - | 39 | - | nC |

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|--------------------------------------|--|--|
| 1 | S | source |  |  |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | |

**SOT669 (LPAK;
Power-SO8)**

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|---------------|--------------------|---|---------|
| | Name | Description | Version |
| PSMN1R1-25YLC | LPAK; Power-SO8 | plastic single-ended surface-mounted package; 4 leads | SOT669 |

4. Marking

Table 4. Marking codes

| Type number | Marking code ^[1] |
|---------------|-----------------------------|
| PSMN1R1-25YLC | 1C125L |

[1] % = placeholder for manufacturing site code.

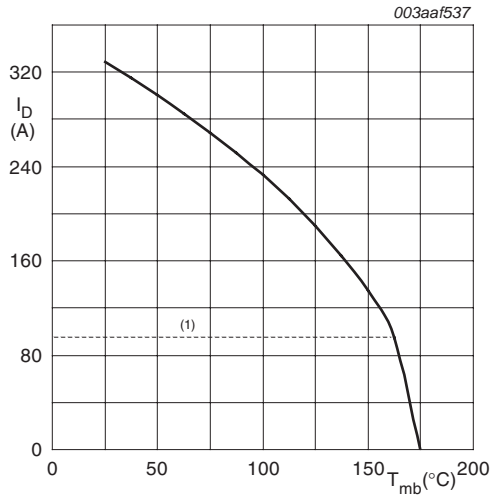
5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

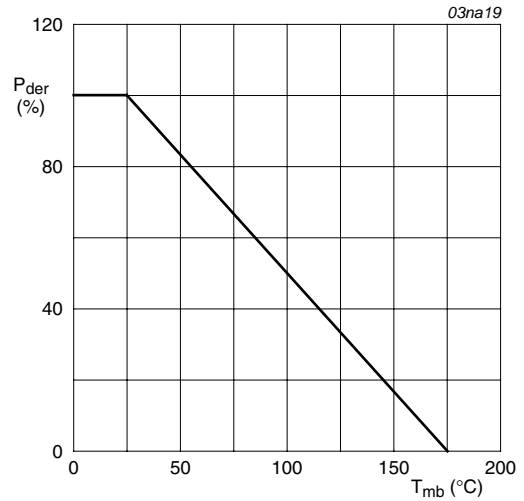
| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------------|--|--|-----|------|------|
| V_{DS} | drain-source voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$ | - | 25 | V |
| V_{DGR} | drain-gate voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$; $R_{GS} = 20\text{ k}\Omega$ | - | 25 | V |
| V_{GS} | gate-source voltage | | -20 | 20 | V |
| I_D | drain current | $V_{GS} = 10\text{ V}$; $T_{mb} = 25\text{ °C}$; see Figure 1 ^[1] | - | 100 | A |
| | | $V_{GS} = 10\text{ V}$; $T_{mb} = 100\text{ °C}$; see Figure 1 ^[1] | - | 100 | A |
| I_{DM} | peak drain current | pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25\text{ °C}$; see Figure 4 | - | 1318 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; see Figure 2 | - | 215 | W |
| T_{stg} | storage temperature | | -55 | 175 | °C |
| T_j | junction temperature | | -55 | 175 | °C |
| $T_{sld(M)}$ | peak soldering temperature | | - | 260 | °C |
| V_{ESD} | electrostatic discharge voltage | MM (JEDEC JESD22-A115) | 810 | - | V |
| Source-drain diode | | | | | |
| I_S | source current | $T_{mb} = 25\text{ °C}$ | - | 100 | A |
| I_{SM} | peak source current | pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25\text{ °C}$ | - | 1318 | A |
| Avalanche ruggedness | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $V_{GS} = 10\text{ V}$; $T_{j(\text{init})} = 25\text{ °C}$; $I_D = 100\text{ A}$; $V_{sup} \leq 25\text{ V}$; unclamped; $R_{GS} = 50\text{ }\Omega$; see Figure 3 | - | 253 | mJ |

[1] Continuous current is limited by package.



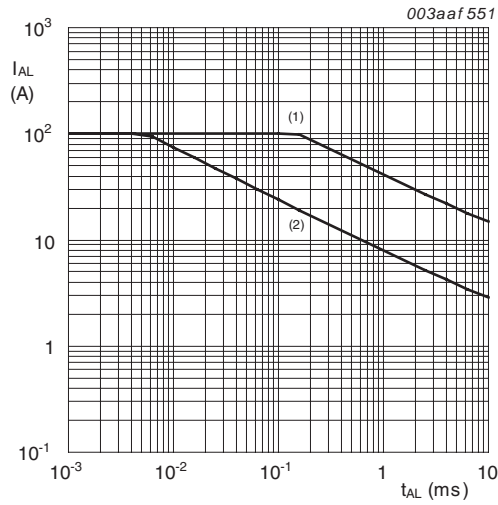
$V_{GS} \geq 10V$; (1) Capped at 100A due to package

Fig 1. Continuous drain current as a function of mounting base temperature



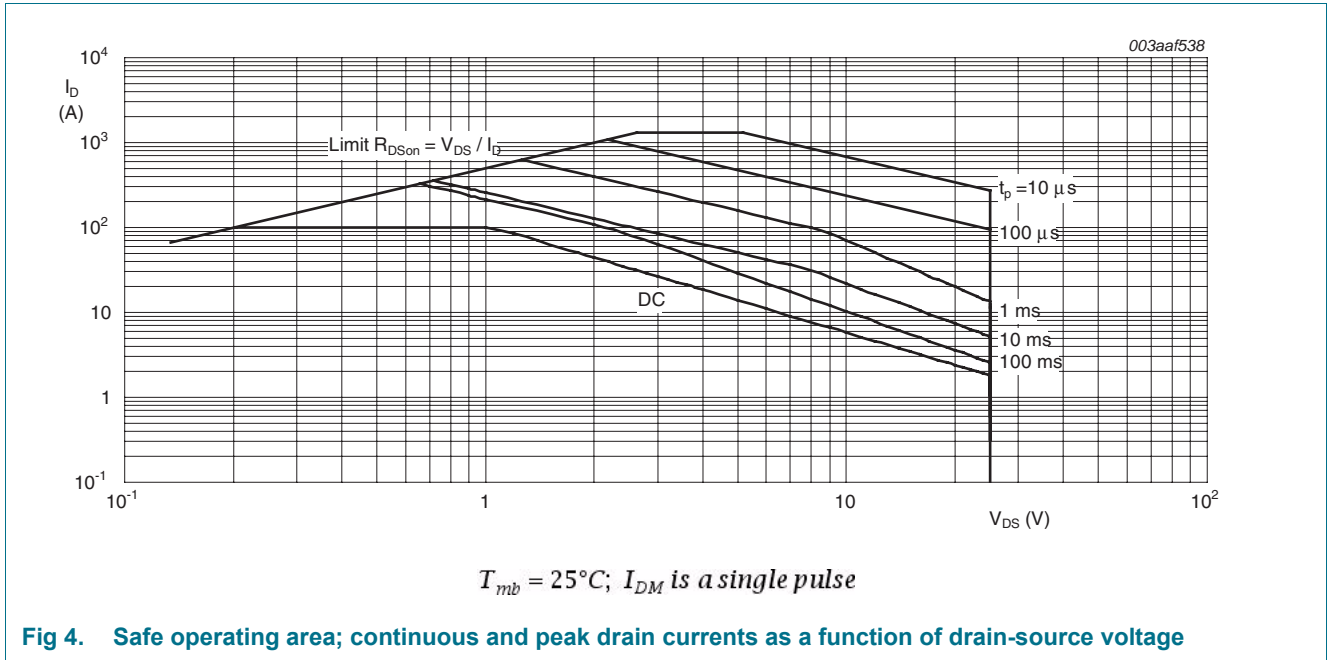
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

Fig 2. Normalized total power dissipation as a function of mounting base temperature



(1) $T_{j(jrr)} = 25^{\circ}C$; (2) $T_{j(jrr)} = 100^{\circ}C$

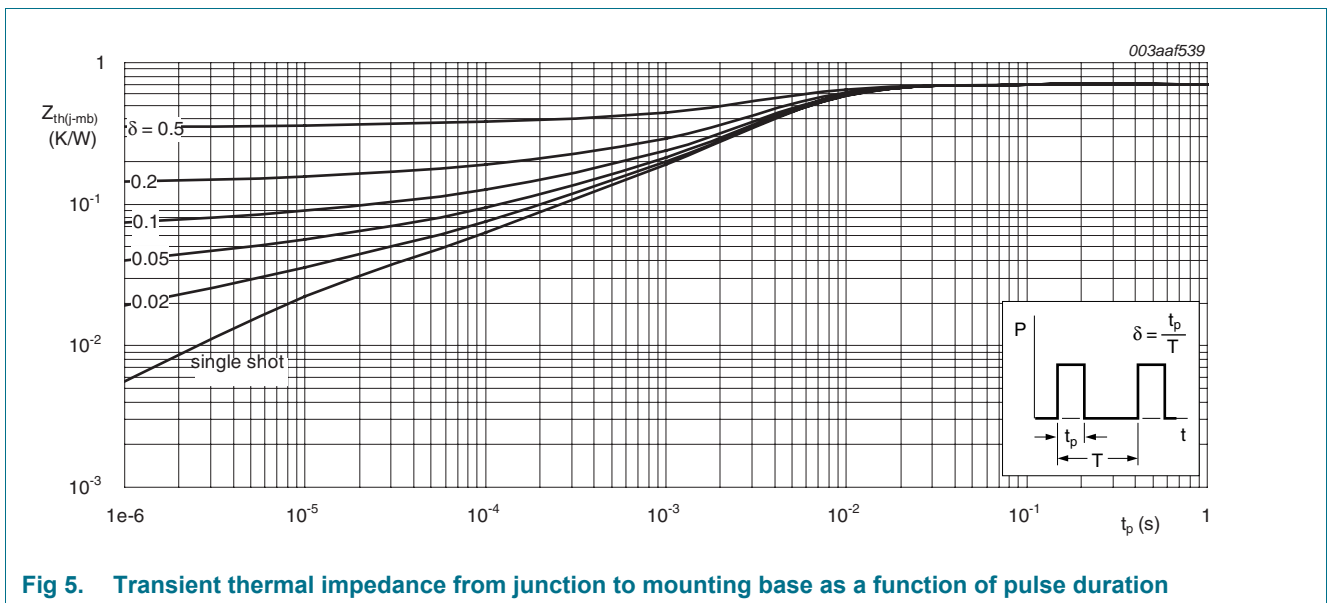
Fig 3. Single pulse avalanche rating; avalanche current as a function of avalanche time



6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------------------------|-----|------|-----|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | see Figure 5 | - | 0.58 | 0.7 | K/W |



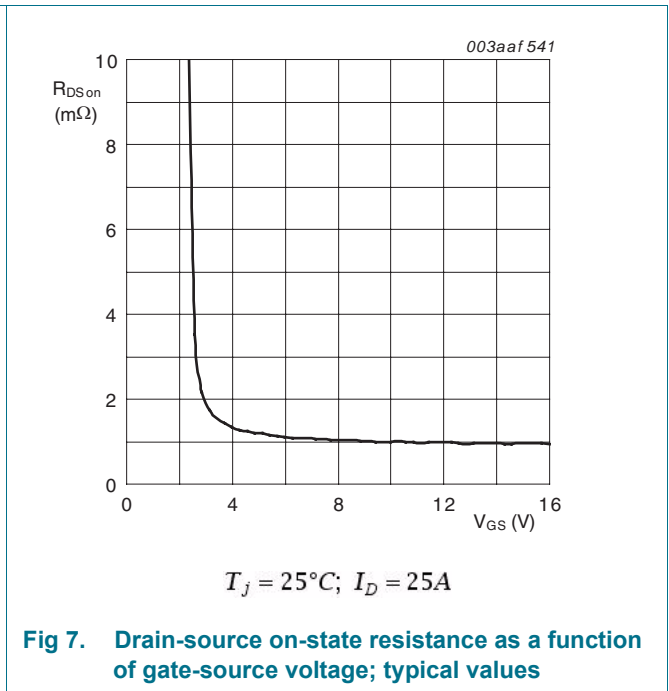
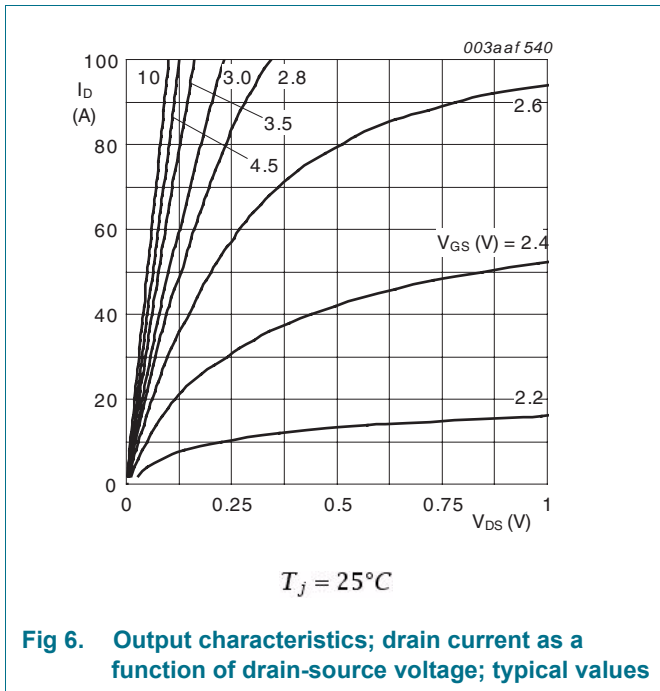
7. Characteristics

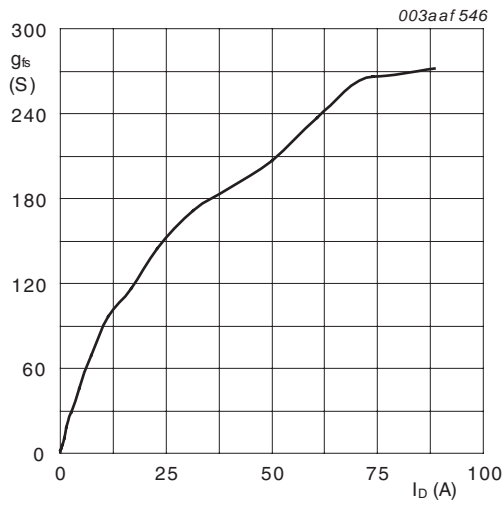
Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------------------------------|--|------|------|------|---------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | 25 | - | - | V |
| | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$ | 22.5 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ C$; see Figure 10 ; see Figure 11 | 1.05 | 1.43 | 1.95 | V |
| | | $I_D = 10 \text{ mA}; V_{DS} = V_{GS}; T_j = 150 \text{ }^\circ C$ | 0.5 | - | - | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ }^\circ C$ | - | - | 2.25 | V |
| I_{DSS} | drain leakage current | $V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | - | 1 | μA |
| | | $V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ }^\circ C$ | - | - | 100 | μA |
| I_{GSS} | gate leakage current | $V_{GS} = 16 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | - | 100 | nA |
| | | $V_{GS} = -16 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | - | 100 | nA |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ C$; see Figure 12 | - | 1.2 | 1.5 | mΩ |
| | | $V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 150 \text{ }^\circ C$; see Figure 13 ; see Figure 12 | - | - | 2.45 | mΩ |
| | | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ C$; see Figure 12 | - | 0.95 | 1.15 | mΩ |
| | | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 150 \text{ }^\circ C$; see Figure 13 ; see Figure 12 | - | - | 1.8 | mΩ |
| R_G | gate resistance | $f = 1 \text{ MHz}$ | - | 1.1 | 2.2 | Ω |
| Dynamic characteristics | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 25 \text{ A}; V_{DS} = 12 \text{ V}; V_{GS} = 10 \text{ V}$; see Figure 14 ; see Figure 15 | - | 83 | - | nC |
| | | $I_D = 25 \text{ A}; V_{DS} = 12 \text{ V}; V_{GS} = 4.5 \text{ V}$; see Figure 15 ; see Figure 14 | - | 39 | - | nC |
| | | $I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$ | - | 75 | - | nC |
| Q_{GS} | gate-source charge | $I_D = 25 \text{ A}; V_{DS} = 12 \text{ V}; V_{GS} = 4.5 \text{ V}$; see Figure 14 ; see Figure 15 | - | 11 | - | nC |
| $Q_{GS(th)}$ | pre-threshold gate-source charge | | - | 8.2 | - | nC |
| $Q_{GS(th-pl)}$ | post-threshold gate-source charge | | - | 2.9 | - | nC |
| Q_{GD} | gate-drain charge | | - | 11 | - | nC |
| $V_{GS(pl)}$ | gate-source plateau voltage | $I_D = 25 \text{ A}; V_{DS} = 12 \text{ V}$; see Figure 14 ; see Figure 15 | - | 2.3 | - | V |
| C_{iss} | input capacitance | $V_{DS} = 12 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}$; | - | 5287 | - | pF |
| C_{oss} | output capacitance | $T_j = 25 \text{ }^\circ C$; see Figure 16 | - | 1121 | - | pF |
| C_{rss} | reverse transfer capacitance | | - | 406 | - | pF |
| $t_{d(on)}$ | turn-on delay time | $V_{DS} = 12 \text{ V}; R_L = 0.5 \text{ } \Omega; V_{GS} = 4.5 \text{ V}$; | - | 35 | - | ns |
| t_r | rise time | $R_{G(ext)} = 4.7 \text{ } \Omega$ | - | 48 | - | ns |
| $t_{d(off)}$ | turn-off delay time | | - | 74 | - | ns |
| t_f | fall time | | - | 36 | - | ns |

Table 7. Characteristics ...continued

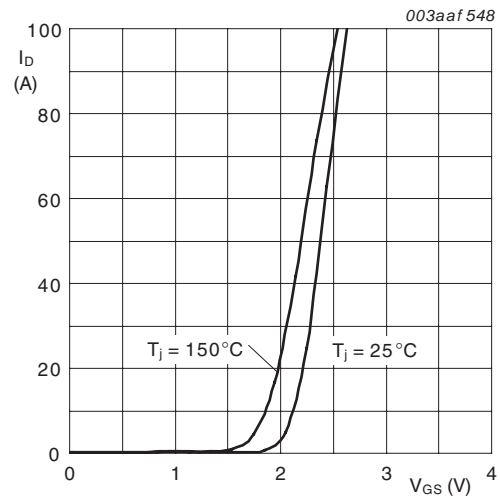
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------------|----------------------------|---|-----|------|-----|------|
| Q_{oss} | output charge | $V_{GS} = 0\text{ V}$; $V_{DS} = 12\text{ V}$; $f = 1\text{ MHz}$; $T_j = 25\text{ °C}$ | - | 22.6 | - | nC |
| Source-drain diode | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 25\text{ A}$; $V_{GS} = 0\text{ V}$; $T_j = 25\text{ °C}$; see Figure 17 | - | 0.8 | 1.1 | V |
| t_{rr} | reverse recovery time | $I_S = 25\text{ A}$; $di_S/dt = -100\text{ A}/\mu\text{s}$; $V_{GS} = 0\text{ V}$; | - | 43 | - | ns |
| Q_r | recovered charge | $V_{DS} = 12\text{ V}$ | - | 42 | - | nC |
| t_a | reverse recovery rise time | $V_{GS} = 0\text{ V}$; $I_S = 25\text{ A}$; $di_S/dt = -100\text{ A}/\mu\text{s}$; $V_{DS} = 12\text{ V}$; see Figure 18 | - | 25 | - | ns |
| t_b | reverse recovery fall time | | - | 18 | - | ns |





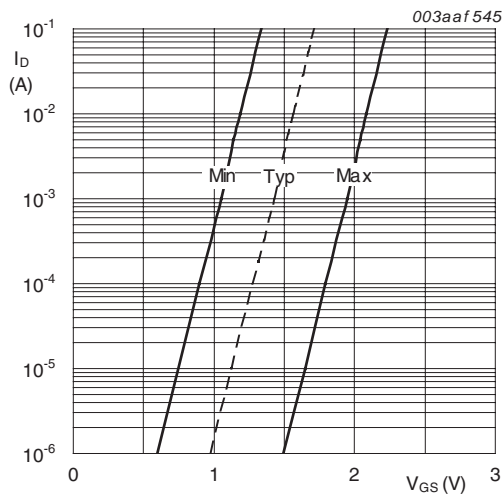
$T_j = 25^\circ\text{C}; V_{DS} = 10\text{V}$

Fig 8. Forward transconductance as a function of drain current; typical values



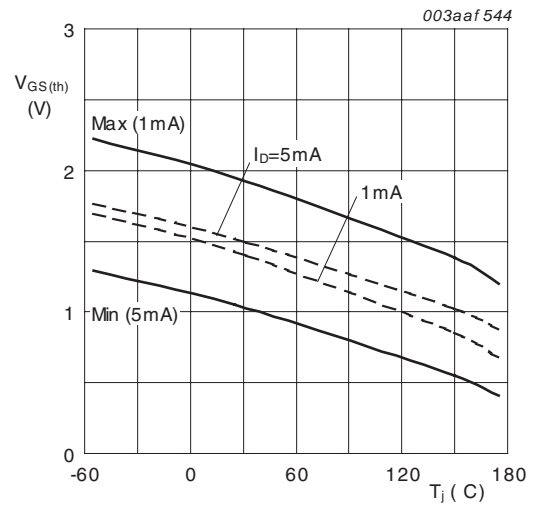
$V_{DS} = 10\text{V}$

Fig 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values



$T_j = 25^\circ\text{C}; V_{DS} = 5\text{V}$

Fig 10. Sub-threshold drain current as a function of gate-source voltage



$V_{DS} = V_{GS}$

Fig 11. Gate-source threshold voltage as a function of junction temperature

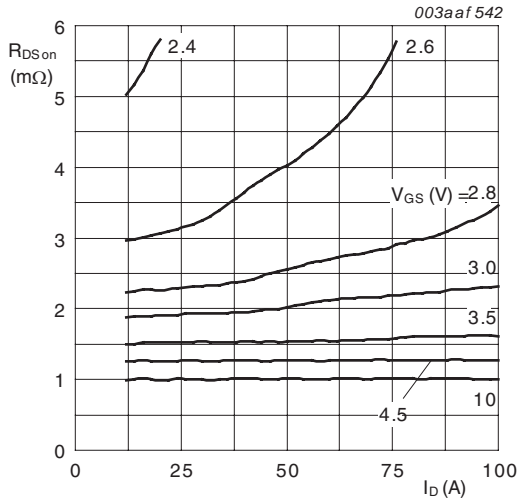
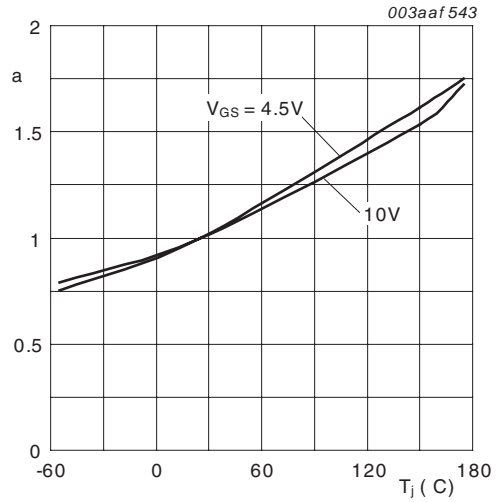


Fig 12. Drain-source on-state resistance as a function of drain current; typical values



$$a = \frac{R_{DSon}}{R_{DSon(25^\circ C)}}$$

Fig 13. Normalized drain-source on-state resistance factor as a function of junction temperature

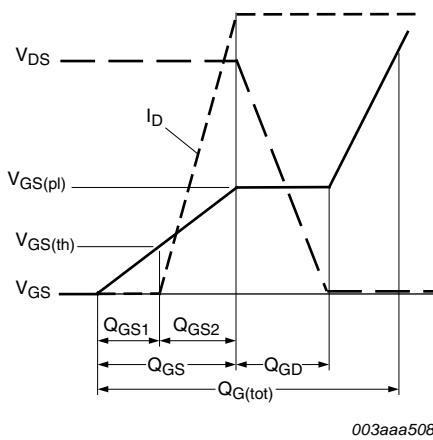


Fig 14. Gate charge waveform definitions

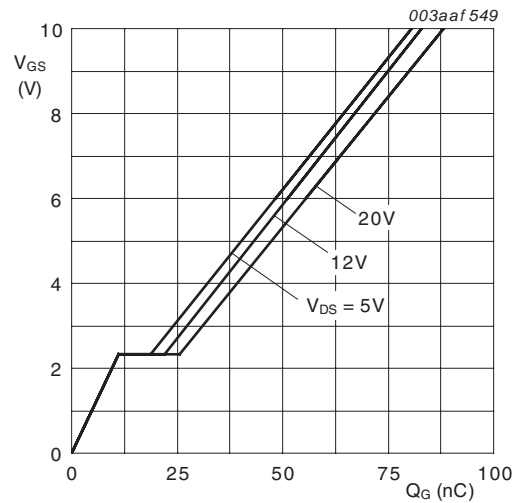
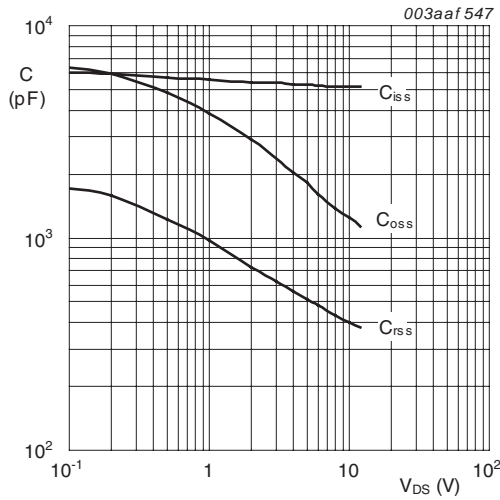
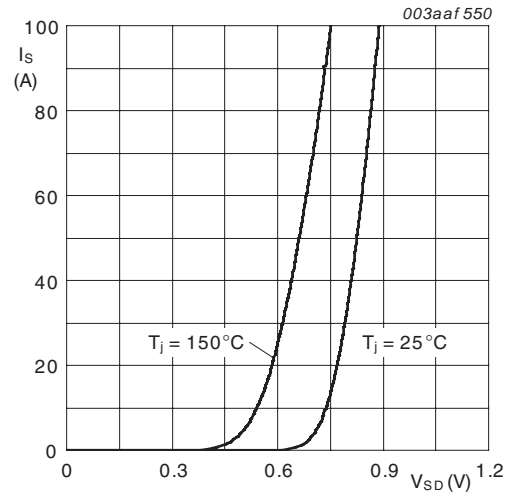


Fig 15. Gate-source voltage as a function of gate charge; typical values



$V_{GS} = 0V; f = 1MHz$

Fig 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$V_{GS} = 0V$

Fig 17. Source current as a function of source-drain voltage; typical values

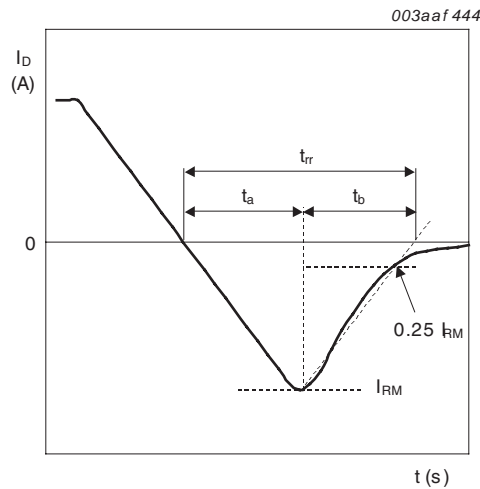


Fig 18. Reverse recovery timing definition

8. Package outline

Plastic single-ended surface-mounted package (LPAK; Power-SO8); 4 leads

SOT669

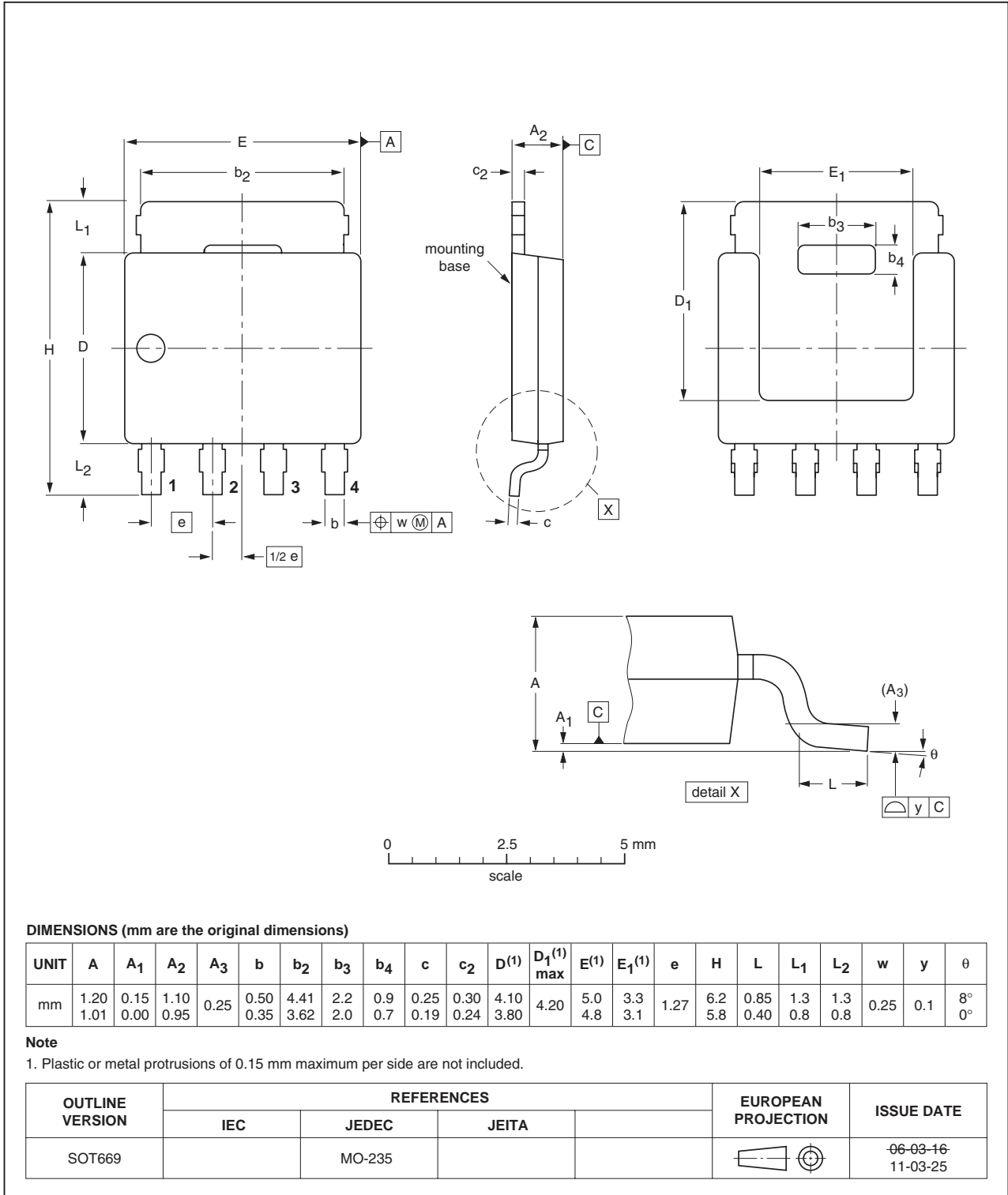


Fig 19. Package outline SOT669 (LPAK; Power-SO8)

9. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------------|--------------|--------------------|---------------|------------|
| PSMN1R1-25YLC v.1 | 20110502 | Product data sheet | - | - |

10. Legal information

10.1 Data sheet status

| Document status [1] [2] | Product status [3] | Definition |
|---|------------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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For sales office addresses, please send an email to: salesaddresses@nexperia.com

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